

# Tim Grieb

## List of Publications by Year in descending order

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Version: 2024-02-01

30  
papers

825  
citations

471509

17  
h-index

501196

28  
g-index

35  
all docs

35  
docs citations

35  
times ranked

1012  
citing authors

#	ARTICLE	IF	CITATIONS
1	Measurement of atomic electric fields and charge densities from average momentum transfers using scanning transmission electron microscopy. Ultramicroscopy, 2017, 178, 62-80.	1.9	106
2	Determination of the chemical composition of GaNAs using STEM HAADF imaging and STEM strain state analysis. Ultramicroscopy, 2012, 117, 15-23.	1.9	79
3	Screening Precursorâ€“Solvent Combinations for Li<sub>4</sub>Ti<sub>5</sub>O<sub>12</sub> Energy Storage Material Using Flame Spray Pyrolysis. ACS Applied Materials & Interfaces, 2017, 9, 37760-37777.	8.0	68
4	Effects of instrument imperfections on quantitative scanning transmission electron microscopy. Ultramicroscopy, 2016, 161, 146-160.	1.9	55
5	Synthesis Route for the Self-Assembly of Submicrometer-Sized Colloidosomes with Tailorable Nanopores. Chemistry of Materials, 2013, 25, 3464-3471.	6.7	47
6	Theoretical study of precision and accuracy of strain analysis by nano-beam electron diffraction. Ultramicroscopy, 2015, 158, 38-48.	1.9	43
7	Materials characterisation by angle-resolved scanning transmission electron microscopy. Scientific Reports, 2016, 6, 37146.	3.3	33
8	Ultrathin Au-Alloy Nanowires at the Liquidâ€“Liquid Interface. Nano Letters, 2018, 18, 1903-1907.	9.1	31
9	Electrical Polarization in AlN/GaN Nanodisks Measured by Momentum-Resolved 4D Scanning Transmission Electron Microscopy. Physical Review Letters, 2019, 122, 106102.	7.8	31
10	Quantitative chemical evaluation of dilute GaNAs using ADF STEM: Avoiding surface strain induced artifacts. Ultramicroscopy, 2013, 129, 1-9.	1.9	29
11	Direct Measurement of Polarization-Induced Fields in GaN/AlN by Nano-Beam Electron Diffraction. Scientific Reports, 2016, 6, 28459.	3.3	25
12	A critical study: Assessment of the effect of silica particles from 15 to 500Ånm on bacterial viability. Environmental Pollution, 2013, 176, 292-299.	7.5	24
13	Influence of plasmon excitations on atomic-resolution quantitative 4D scanning transmission electron microscopy. Scientific Reports, 2020, 10, 17890.	3.3	21
14	Simultaneous Quantification of Indium and Nitrogen Concentration in InGaAs Using HAADF-STEM. Microscopy and Microanalysis, 2014, 20, 1740-1752.	0.4	20
15	Quantitative Characterization of Nanometer-Scale Electric Fields via Momentum-Resolved STEM. Nano Letters, 2021, 21, 2018-2025.	9.1	20
16	Coherently Embedded Ag Nanostructures in Si: 3D Imaging and their application to SERS. Scientific Reports, 2014, 4, 4633.	3.3	19
17	Quantitative HAADF STEM of SiGe in presence of amorphous surface layers from FIB preparation. Ultramicroscopy, 2018, 184, 29-36.	1.9	17
18	Strain analysis from nano-beam electron diffraction: Influence of specimen tilt and beam convergence. Ultramicroscopy, 2018, 190, 45-57.	1.9	17

#	ARTICLE	IF	CITATIONS
19	Using molecular dynamics for multislice TEM simulation of thermal diffuse scattering in AlGaIn. Ultramicroscopy, 2018, 189, 124-135.	1.9	16
20	Influence of distortions of recorded diffraction patterns on strain analysis by nano-beam electron diffraction. Ultramicroscopy, 2019, 196, 74-82.	1.9	15
21	Optimization of NBED simulations for disc-detection measurements. Ultramicroscopy, 2017, 181, 50-60.	1.9	13
22	Bias-Controlled Optical Transitions in GaN/AlN Nanowire Heterostructures. ACS Nano, 2017, 11, 8758-8767.	14.6	10
23	Measurement of local crystal lattice strain variations in dealloyed nanoporous gold. Materials Research Letters, 2018, 6, 84-92.	8.7	10
24	Accurate measurement of strain at interfaces in 4D-STEM: A comparison of various methods. Ultramicroscopy, 2021, 221, 113196.	1.9	10
25	4D-STEM at interfaces to GaN: Centre-of-mass approach & NBED-disc detection. Ultramicroscopy, 2021, 228, 113321.	1.9	9
26	Angle-resolved STEM using an iris aperture: Scattering contributions and sources of error for the quantitative analysis in Si. Ultramicroscopy, 2021, 221, 113175.	1.9	8
27	Towards the interpretation of a shift of the central beam in nano-beam electron diffraction as a change in mean inner potential. Ultramicroscopy, 2022, 236, 113503.	1.9	6
28	Angle-dependence of ADF-STEM intensities for chemical analysis of InGaIn/GaN. Ultramicroscopy, 2022, 238, 113535.	1.9	4
29	Accuracy and precision of position determination in ISTEM imaging of BaTiO <sub>3</sub> . Ultramicroscopy, 2021, 227, 113325.	1.9	2
30	Quantitative characterization of nanometer-scale electric fields via momentum-resolved STEM. Microscopy and Microanalysis, 2021, 27, 2206-2207.	0.4	0